2SA1296 TRANSISTOR (PNP)

TO-92

1.EMITTER
2.COLLECTOR
3.BASE

FEATURES

- Low Saturation Voltage: $V_{CE\ (sat)}$
- High DC Current Gain

ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
2SA1296	TO-92	Bulk	1000pcs/Bag
2SA1296-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-20	V
V_{CEO}	Collector-Emitter Voltage	-20	V
V_{EBO}	Emitter-Base Voltage	-6	V
I_C	Collector Current -Continuous	-2	A
P_D	Collector Power Dissipation	750	mW
R_{KJA}	Thermal Resistance from Junction to Ambient	166	℃ /W
T_J,T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	℃

T_a=25℃ unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C= -0.1mA,I_E=0	-20			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I_C=-10mA,I_B=0	-20			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E=-0.1mA,I_C=0	-6			V
Collector cut-off current	I_{CBO}	V_{CB}=-20V,I_E=0			-0.1	7A
Emitter cut-off current	I_{EBO}	V_{EB}=-6V,I_C=0			-0.1	7A
DC current gain	$h_{FE(1)}$	V_{CE}=-2V, I_C=-0.1A	120		400	
	$h_{FE(2)}$	V_{CE}=-2V, I_C=-2A	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C=-2A,I_B=-0.1A			-0.5	V
Base-emitter voltage	V_{BE}	V_{CE}=-2V, I_C=-0.1A			-0.85	V
Collector output capacitance	C_{ob}	V_{CB}=-10V,I_E=0, f=1MHz		40		pF
Transition frequency	f_T	V_{CE}=-2V,I_C=-0.5A		120		MHz

CLASSIFICATION OF $h_{FE(1)}$

RANK	Y	GR
RANGE	120-240	200-400